



PNP SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

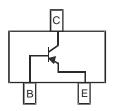
- **Epitaxial Planar Die Construction**
- Complementary NPN Type Available (MMBT2222A)
- Ideal for Low Power Amplification and Switching
- Lead, Halogen and Antimony Free, RoHS Compliant (Note 2)
- "Green" Device (Note 3)
- Qualified to AEC-Q 101 Standards for High Reliability

Mechanical Data

- Case: SOT-23
- Case Material: Molded Plastic, "Green" Molding Compound, Note 3. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminal Connections: See Diagram
- Terminals: Matte Tin Finish annealed over Alloy 42 leadframe (Lead Free Plating) Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.008 grams (approximate)







Device Schematic

Maximum Ratings @TA = 25°C unless otherwise specified

| Characteristic | Symbol | Value | Unit |
|---|------------------|-------|------|
| Collector-Base Voltage | V_{CBO} | -60 | V |
| Collector-Emitter Voltage | V _{CEO} | -60 | V |
| Emitter-Base Voltage | V _{EBO} | -5.0 | V |
| Collector Current - Continuous (Note 1) | Ic | -600 | mA |
| Peak Collector Current | I _{CM} | -800 | mA |

Thermal Characteristics

| Characteristic | Symbol | Value | Unit |
|--|-----------------------------------|-------------|------|
| Power Dissipation (Note 1) | P _D | 300 | mW |
| Thermal Resistance, Junction to Ambient (Note 1) | $R_{	heta JA}$ | 417 | °C/W |
| Operating and Storage and Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

Notes:

- 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- No purposefully added lead. Halogen and Antimony Free
 Product manufactured with Data Code V9 (week 33, 2008) and newer are built with Green Molding Compound. Product manufactured prior to Date Code V9 are built with Non-Green Molding Compound and may contain Halogens or Sb₂O₃ Fire Retardants.



Electrical Characteristics @T_A = 25°C unless otherwise specified

| Characteristic | Symbol | Min | Max | Unit | Test Condition | | |
|--------------------------------------|-----------------------|-----------|------|------|--|--|--|
| OFF CHARACTERISTICS (Note 4) | | | | | | | |
| Collector-Base Breakdown Voltage | V _{(BR)CBO} | -60 | _ | V | $I_C = -10\mu A, I_E = 0$ | | |
| Collector-Emitter Breakdown Voltage | V _{(BR)CEO} | -60 | | V | $I_C = -10 \text{mA}, I_B = 0$ | | |
| Emitter-Base Breakdown Voltage | $V_{(BR)EBO}$ | -5.0 | | V | $I_E = -10\mu A, I_C = 0$ | | |
| Collector Cutoff Current | I _{CBO} | _ | -10 | nA | $V_{CB} = -50V, I_{E} = 0$ | | |
| Conector Cuton Current | | | | μΑ | $V_{CB} = -50V$, $I_E = 0$, $T_A = 125$ °C | | |
| Collector Cutoff Current | I _{CEX} | | -50 | nA | $V_{CE} = -30V, V_{EB(OFF)} = -0.5V$ | | |
| Base Cutoff Current | I_{BL} | _ | -50 | nA | $V_{CE} = -30V, V_{EB(OFF)} = -0.5V$ | | |
| ON CHARACTERISTICS (Note 4) | | | - | | | | |
| | | 75 | _ | | $I_C = -100 \mu A, V_{CE} = -10 V$ | | |
| | | 100 | _ | | $I_C = -1.0 \text{mA}, V_{CE} = -10 \text{V}$ | | |
| DC Current Gain | h_{FE} | 100 | _ | _ | $I_C = -10 \text{mA}, V_{CE} = -10 \text{V}$ | | |
| | | 100 50 | 300 | | $I_C = -150 \text{mA}, V_{CE} = -10 \text{V}$ | | |
| | | 50 | _ | | $I_C = -500 \text{mA}, V_{CE} = -10 \text{V}$ | | |
| Collector-Emitter Saturation Voltage | V _{CE} (SAT) | _ | -0.4 | V | $I_C = -150 \text{mA}, I_B = -15 \text{mA}$ | | |
| Concolor Emilior Calaration Voltage | | | -1.6 | | $I_C = -500 \text{mA}, I_B = -50 \text{mA}$ | | |
| Base-Emitter Saturation Voltage | V _{BE(SAT)} | _ | -1.3 | V | $I_C = 150 \text{mA}, I_B = 15 \text{mA}$ | | |
| <u> </u> | V BE(SAT) | | -2.6 | · · | $I_C = 500 \text{mA}, I_B = 50 \text{mA}$ | | |
| SMALL SIGNAL CHARACTERISTICS | | | | 1 | + | | |
| Output Capacitance | C_{obo} | | 8.0 | pF | $V_{CB} = -10V, f = 1.0MHz, I_E = 0$ | | |
| Input Capacitance | C _{ibo} | | 30 | pF | $V_{EB} = -2.0V$, $f = 1.0MHz$, $I_{C} = 0$ | | |
| Current Gain-Bandwidth Product | f _T | 200 | | MHz | $V_{CE} = -20V, I_{C} = -50mA,$ f = 100MHz | | |
| SWITCHING CHARACTERISTICS | | | | - | | | |
| Turn-On Time | t _{off} | _ | 45 | ns | | | |
| Delay Time | t _d | | 10 | ns | $V_{CC} = -30V, I_C = -150mA,$ | | |
| Rise Time | t _r | _ | 40 | ns | I _{B1} = -15mA | | |
| Turn-Off Time | t _{off} | | 100 | ns | V _{CC} = -6.0V, I _C = -150mA, | | |
| Storage Time | ts | | 80 | ns | $V_{CC} = -6.0V$, $I_{C} = -150\text{mA}$, $I_{B1} = I_{B2} = -15\text{mA}$ | | |
| Fall Time | t _f | _ | 30 | ns | | | |

Notes: 4. Short duration pulse test used to minimize self-heating effect.

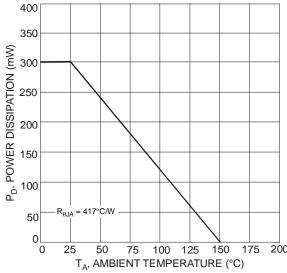


Fig. 1 Power Dissipation vs. Ambient Temperature (Note 1)

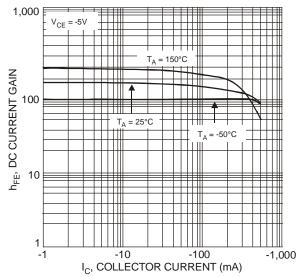


Fig. 2 Typical DC Current Gain vs. Collector Current



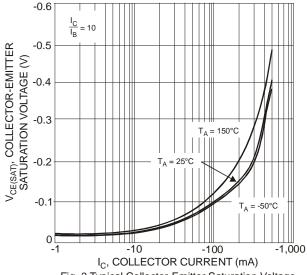
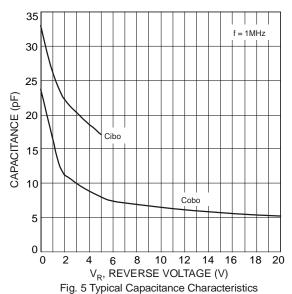


Fig. 3 Typical Collector-Emitter Saturation Voltage vs. Collector Current



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Fig. 7 Typical Collector Saturation Region

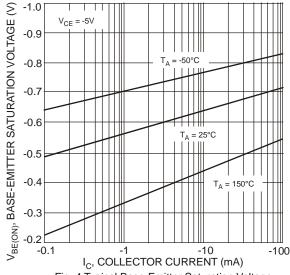


Fig. 4 Typical Base-Emitter Saturation Voltage vs. Collector Current

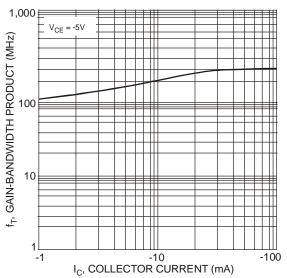


Fig. 6 Typical Gain-Bandwidth Product vs. Collector Current

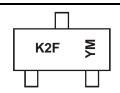


Ordering Information (Note 5)

| Part Number | Case | Packaging |
|---------------|--------|------------------|
| MMBT2907A-7-F | SOT-23 | 3000/Tape & Reel |

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



K2F = Product Type Marking Code YM = Date Code Marking

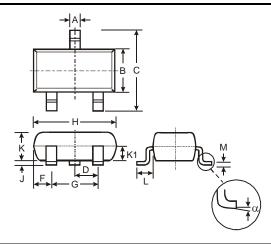
Y = Year (ex: N = 2002)

M = Month (ex: 9 = September)

Date Code Key

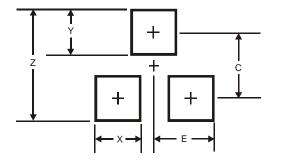
| Year | 1998 | 1999 | 2000 | 2001 | 2002 | 2003 | 2004 | 2005 | 2006 | 2007 | 2008 | 2009 | 2010 | 2011 | 2012 | 2013 | 2014 | 2015 |
|-------|------|------|------|------|------|------|------|------|------|------|------|------|------|------|------|------|------|------|
| Code | J | K | L | M | N | Р | R | S | T | U | V | W | X | Υ | Z | Α | В | С |
| Month | Jan | 1 | Feb | Mai | r | Apr | May | / | Jun | Jul | I . | Aug | Sep | | Oct | Nov | , | Dec |
| Code | 1 | | 2 | 3 | | 4 | 5 | | 6 | 7 | | 8 | 9 | | 0 | N | | D |

Package Outline Dimensions



| SOT-23 | | | | | | | |
|----------------------|-------|------------|-------|--|--|--|--|
| Dim | Min | Min Max Ty | | | | | |
| Α | 0.37 | 0.51 | 0.40 | | | | |
| В | 1.20 | 1.40 | 1.30 | | | | |
| C | 2.30 | 2.50 | 2.40 | | | | |
| D | 0.89 | 1.03 | 0.915 | | | | |
| F | 0.45 | 0.60 | 0.535 | | | | |
| G | 1.78 | 2.05 | 1.83 | | | | |
| Н | 2.80 | 3.00 | 2.90 | | | | |
| 7 | 0.013 | 0.10 | 0.05 | | | | |
| K | 0.903 | 0.903 1.10 | | | | | |
| K1 | - | 1 | 0.400 | | | | |
| L | 0.45 | 0.61 | 0.55 | | | | |
| М | 0.085 | 0.18 | 0.11 | | | | |
| α | 0° | 8° | - | | | | |
| All Dimensions in mm | | | | | | | |

Suggested Pad Layout



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 2.9 |
| Х | 0.8 |
| Υ | 0.9 |
| С | 2.0 |
| E | 1.35 |

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